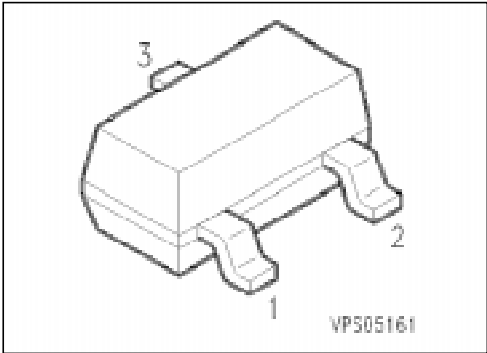


NPN Silicon AF Transistors

BC 846 ... BC 850

Features

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BC 856, BC 857, BC 859, BC 860 (PNP)



Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package ¹⁾
			1	2	3	
BC 846 A	1As	Q62702-C1772	B	E	C	SOT-23
BC 846 B	1Bs	Q62702-C1746				
BC 847 A	1Es	Q62702-C1884				
BC 847 B	1Fs	Q62702-C1687				
BC 847 C	1Gs	Q62702-C1715				
BC 848 A	1Js	Q62702-C1741				
BC 848 B	1Ks	Q62702-C1704				
BC 848 C	1Ls	Q62702-C1506				
BC 849 B	2Bs	Q62702-C1727				
BC 849 C	2Cs	Q62702-C1713				
BC 850 B	2Fs	Q62702-C1885				
BC 850 C	2Gs	Q62702-C1712				

¹⁾For detailed information see chapter Package Outlines.

Maximum Ratings

Parameter	Symbol	Values			Unit
		BC 846	BC 847 BC 850	BC 848 BC 849	
Collector-emitter voltage	V_{CE0}	65	45	30	V
Collector-base voltage	V_{CB0}	80	50	30	
Collector-emitter voltage	V_{CES}	80	50	30	
Emitter-base voltage	V_{EB0}	6	6	5	
Collector current	I_C	100			mA
Peak collector current	I_{CM}	200			
Peak base current	I_{BM}	200			
Peak emitter current	I_{EM}	200			
Total power dissipation, $T_S = 71\text{ °C}$	P_{tot}	330			mW
Junction temperature	T_j	150			°C
Storage temperature range	T_{stg}	− 65 ... + 150			

Thermal Resistance

Junction - ambient ¹⁾	$R_{th JA}$	≤ 310	K/W
Junction - soldering point	$R_{th JS}$	≤ 240	

¹⁾Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristics

at $T_A = 25\text{ °C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC characteristics

Collector-emitter breakdown voltage $I_C = 10\text{ mA}$ BC 846 BC 847, BC 850 BC 848, BC 849	$V_{(BR)CE0}$	65 45 30	— — —	— — —	V
Collector-base breakdown voltage $I_C = 10\text{ }\mu\text{A}$ BC 846 BC 847, BC 850 BC 848, BC 849	$V_{(BR)CB0}$	80 50 30	— — —	— — —	
Collector-emitter breakdown voltage $I_C = 10\text{ }\mu\text{A}$, $V_{BE} = 0$ BC 846 BC 847, BC 850 BC 848, BC 849	$V_{(BR)CES}$	80 50 30	— — —	— — —	
Emitter-base breakdown voltage $I_E = 1\text{ }\mu\text{A}$ BC 846, BC 847 BC 848, BC 849, BC 850	$V_{(BR)EB0}$	6 5	— —	— —	
Collector cutoff current $V_{CB} = 30\text{ V}$ $V_{CB} = 30\text{ V}$, $T_A = 150\text{ °C}$	I_{CB0}	— —	— —	15 5	nA μA
DC current gain $I_C = 10\text{ }\mu\text{A}$, $V_{CE} = 5\text{ V}$ BC 846 A, BC 847 A, BC 848 A BC 846 B ... BC 850 B BC 847 C, BC 848 C, BC 849 C, BC 850 C $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$ BC 846 A, BC 847 A, BC 848 A BC 846 B ... BC 850 B BC 847 C, BC 848 C, BC 849 C, BC 850 C	h_{FE}	— — — 110 200 420	140 250 480 180 290 520	— — — 220 450 800	—
Collector-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$ $I_C = 100\text{ mA}$, $I_B = 5\text{ mA}$	V_{CEsat}	— —	90 200	250 600	mV
Base-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$ $I_C = 100\text{ mA}$, $I_B = 5\text{ mA}$	V_{BEsat}	— —	700 900	— —	
Base-emitter voltage $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$ $I_C = 10\text{ mA}$, $V_{CE} = 5\text{ V}$	$V_{BE(on)}$	580 —	660 —	700 770	

¹⁾Pulse test: $t \leq 300\text{ }\mu\text{s}$, $D = 2\text{ %}$.

Electrical Characteristics

at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

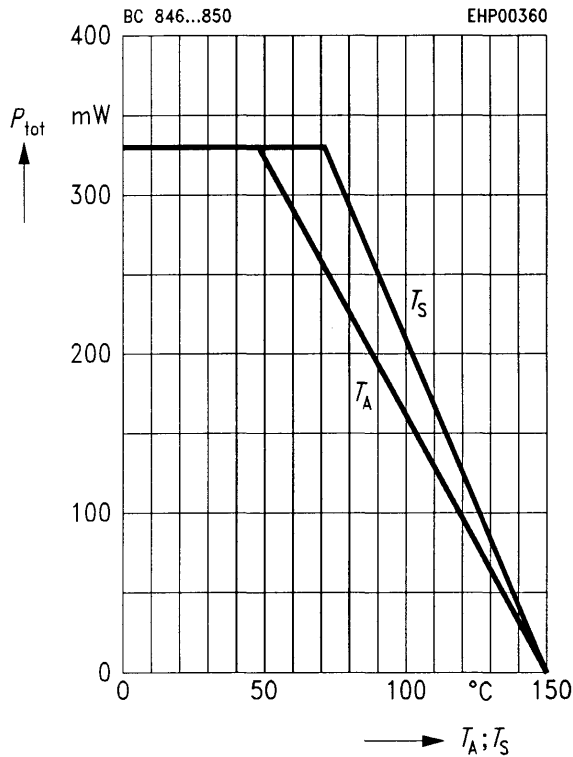
Parameter	Symbol	Values			Unit
		min.	typ.	max.	

AC characteristics

Transition frequency $I_C = 20\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 100\text{ MHz}$	f_T	—	250	—	MHz
Output capacitance $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{obo}	—	3	—	pF
Input capacitance $V_{CB} = 0.5\text{ V}$, $f = 1\text{ MHz}$	C_{ibo}	—	8	—	
Short-circuit input impedance $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{11e}	— — —	2.7 4.5 8.7	— — —	k Ω
Open-circuit reverse voltage transfer ratio $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{12e}	— — —	1.5 2.0 3.0	— — —	10^{-4}
Short-circuit forward current transfer ratio $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{21e}	— — —	200 330 600	— — —	—
Open-circuit output admittance $I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$, $f = 1\text{ kHz}$ BC 846 A ... BC 848 A BC 846 B ... BC 850 B BC 847 C ... BC 850 C	h_{22e}	— — —	18 30 60	— — —	μS
Noise figure $I_C = 0.2\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_S = 2\text{ k}\Omega$ $f = 30\text{ Hz} \dots 15\text{ kHz}$ BC 849 BC 850 $f = 1\text{ kHz}$, $\Delta f = 200\text{ Hz}$ BC 849 BC 850	F	— — — —	1.4 1.4 1.2 1.0	4 3 4 4	dB
Equivalent noise voltage $I_C = 0.2\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_S = 2\text{ k}\Omega$ $f = 10\text{ Hz} \dots 50\text{ Hz}$ BC 850	V_n	—	—	0.135	μV

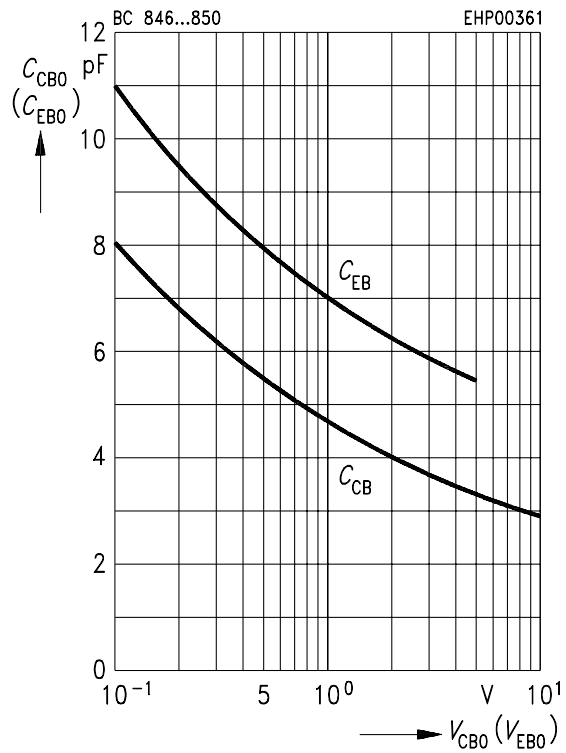
Total power dissipation $P_{\text{tot}} = f(T_A^*; T_S)$

* Package mounted on epoxy

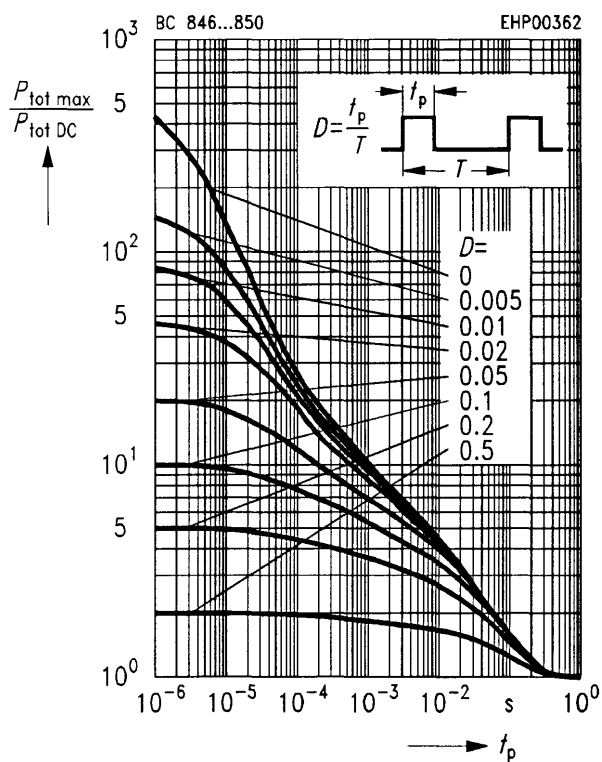


Collector-base capacitance $C_{CB0} = f(V_{CB0})$

Emitter-base capacitance $C_{EB0} = f(V_{EB0})$

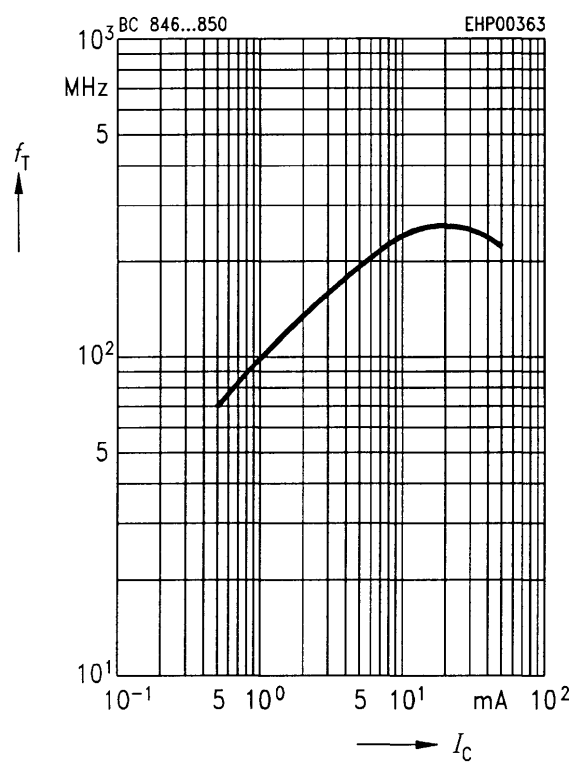


Permissible pulse load $P_{\text{tot max}}/P_{\text{tot DC}} = f(t_p)$



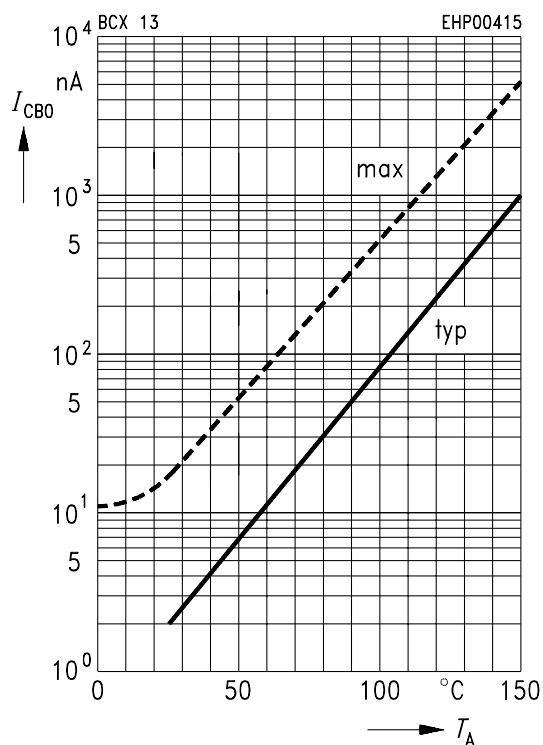
Transition frequency $f_T = f(I_C)$

$V_{CE} = 5 \text{ V}$



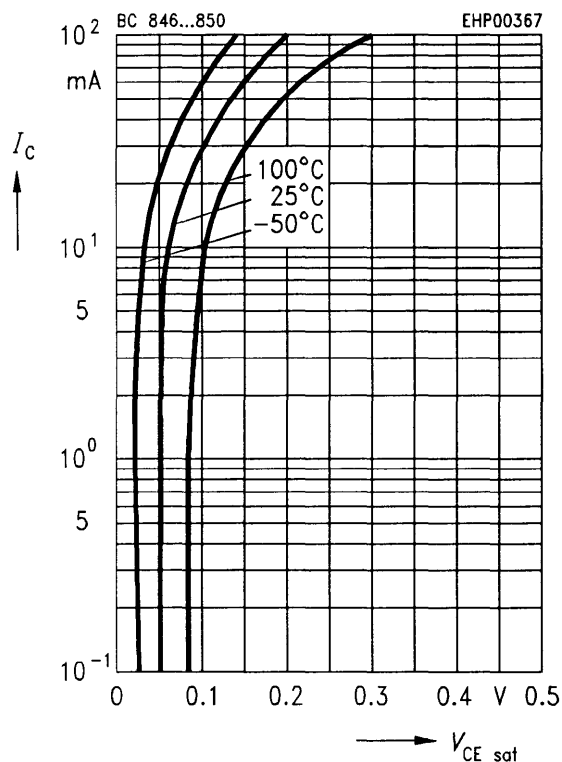
Collector cutoff current $I_{CB0} = f(T_A)$

$V_{CB} = 30 \text{ V}$



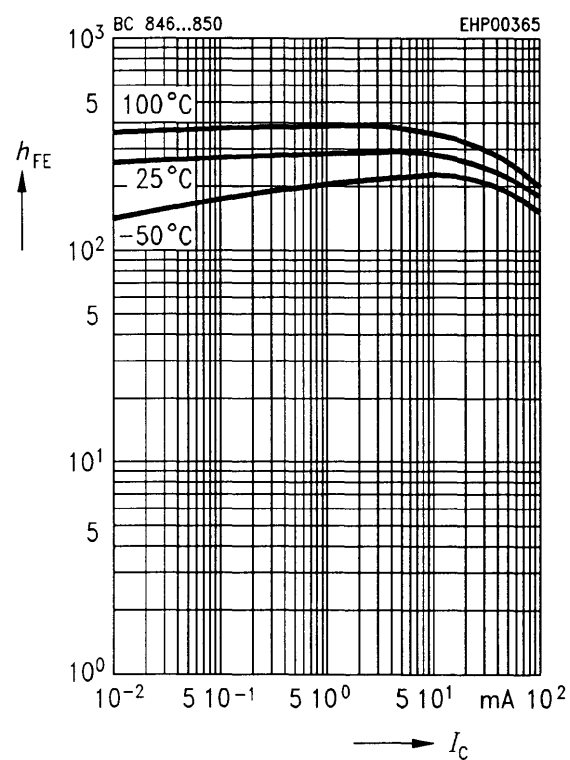
Collector-emitter saturation voltage

$I_C = f(V_{CEsat}), h_{FE} = 20$



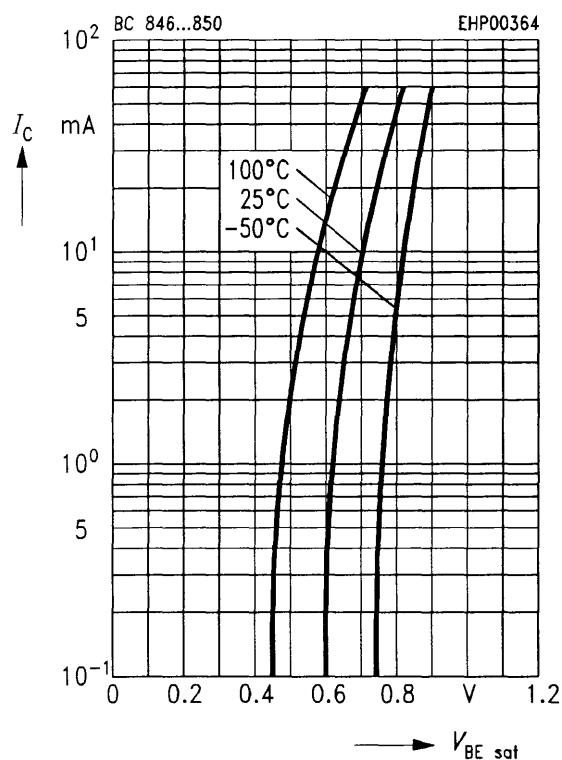
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5 \text{ V}$



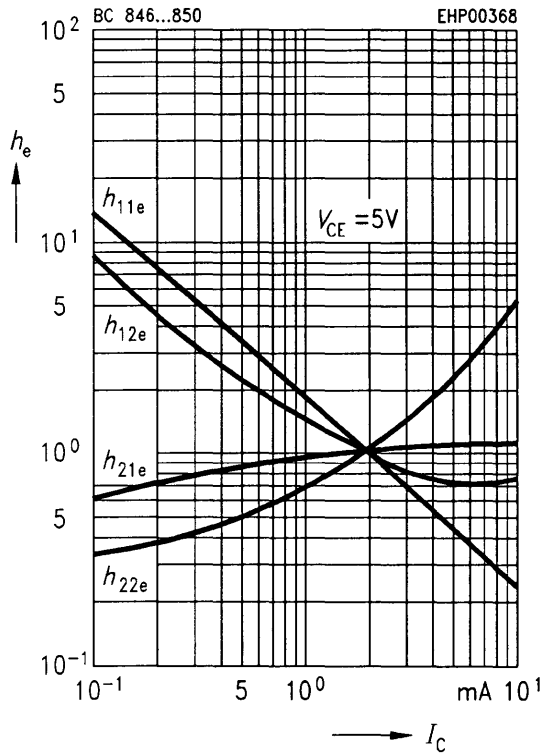
Base-emitter saturation voltage

$I_C = f(V_{BEsat}), h_{FE} = 20$



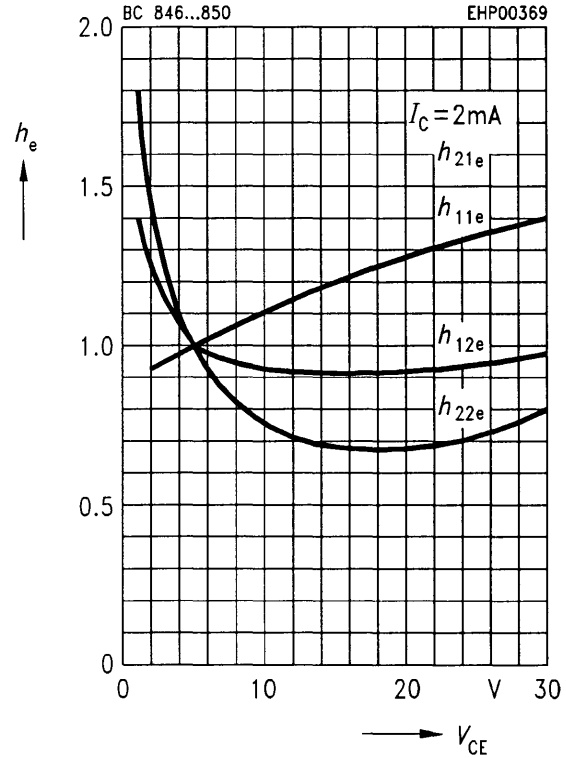
h parameter $h_e = f(I_C)$ normalized

$V_{CE} = 5 \text{ V}$



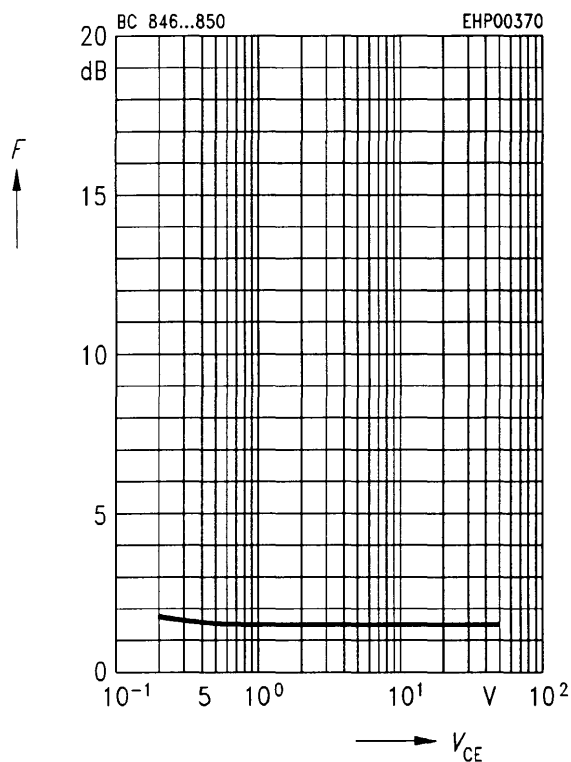
h parameter $h_e = f(V_{CE})$ normalized

$I_C = 2 \text{ mA}$



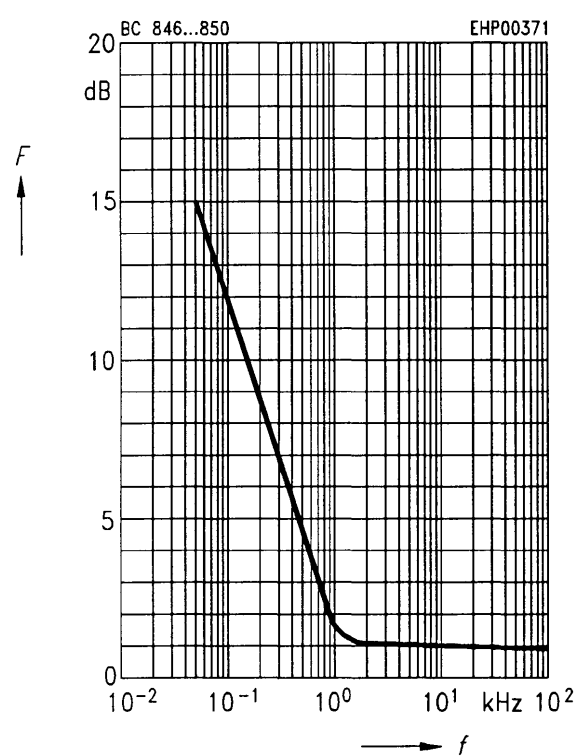
Noise figure $F = f(V_{CE})$

$I_C = 0.2 \text{ mA}$, $R_S = 2 \text{ k}\Omega$, $f = 1 \text{ kHz}$



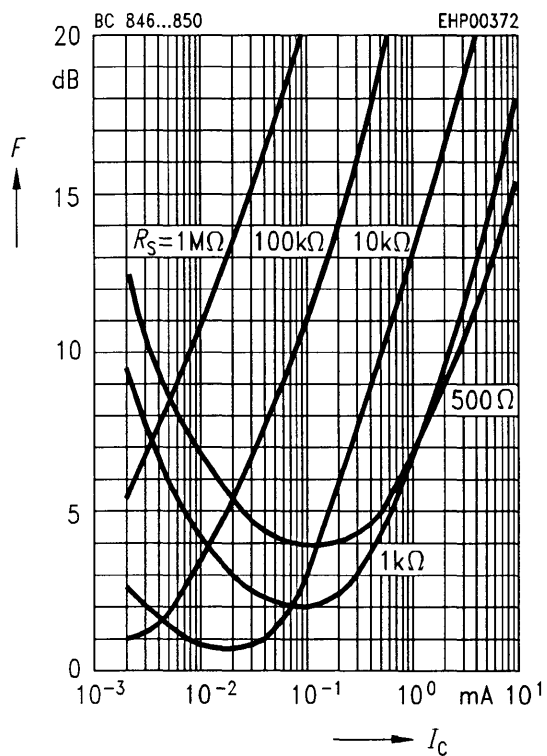
Noise figure $F = f(f)$

$I_C = 0.2 \text{ mA}$, $V_{CE} = 5 \text{ V}$, $R_S = 2 \text{ k}\Omega$



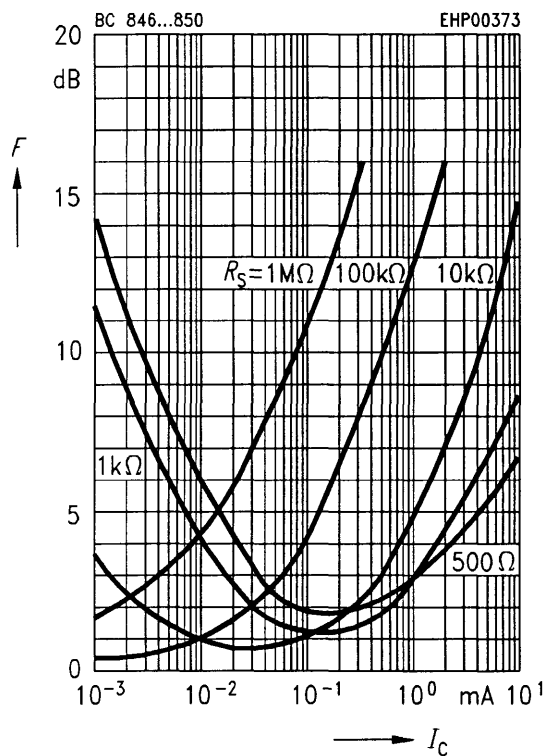
Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 120 \text{ Hz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 1 \text{ kHz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 10 \text{ kHz}$

